

### Vishay General Semiconductor

# **Dual Common Cathode High Voltage Schottky Rectifier**

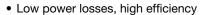


PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 30 A			
V <sub>RRM</sub>	100 V			
I <sub>FSM</sub>	350 A			
V <sub>F</sub> at I <sub>F</sub> = 30 A	0.64 V			
T <sub>J</sub> max.	175 °C			
Package	TO-220AB			
Diode variations	Common cathode			

#### **FEATURES**







Low forward voltage drop

• High forward surge capability

• High frequency operation

• Solder dip 260 °C, 40 s

 Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB

Epoxy meets UL 94 V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A

whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PARAMETER		SYMBOL	MBR60100CT	UNIT
Maximum repetitive peak reverse voltage		$V_{RRM}$	100	V
Working peak reverse voltage		$V_{RWM}$	100	V
Maximum DC blocking voltage		V <sub>DC</sub>	100	V
Maximum average forward rectified current	total device		60	А
	per diode	I <sub>F(AV)</sub>	30	
Peak forward surge current 8.3 ms single half sine-wave supering on rated load per diode	nposed	I <sub>FSM</sub>	350	Α
Peak repetitive reverse current per diode at $t_p = 2 \mu s$ , 1 kHz		I <sub>RRM</sub>	1.0	Α
Peak non-repetitive reverse surge energy per diode (8/20 µs waveform)		E <sub>RSM</sub>	25	mJ
Non-repetitive avalanche energy per diode at 25 °C, I <sub>AS</sub> = 1.0 A, L = 40 mH		E <sub>AS</sub>	20	mJ
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 175	°C



# Vishay General Semiconductor

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltageper diode (1)	I <sub>F</sub> = 30 A	T <sub>J</sub> = 25 °C	V <sub>F</sub>	0.78	0.82	V	
	I <sub>F</sub> = 60 A			0.92	1		
	I <sub>F</sub> = 30 A	T <sub>J</sub> = 125 °C		0.64	0.69		
	I <sub>F</sub> = 60 A		IJ = 125 C	0.78	0.83		
Reverse current per diode (2)	V <sub>R</sub> = 100 V	$T_J = 25  ^{\circ}\text{C}$ $T_{.1} = 125  ^{\circ}\text{C}$		8	100	μΑ	
		T <sub>J</sub> = 125 °C	I <sub>R</sub>	8.5	20	mA	

#### **Notes**

(1) Pulse test: 300µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	MBR60100CT	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	0.5	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR60100CT-E3/45	2.068	45	50/tube	Tube	

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

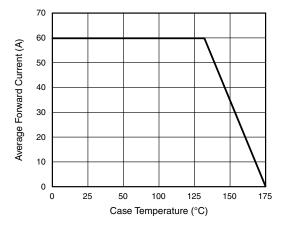


Fig. 1 - Forward Derating Curve

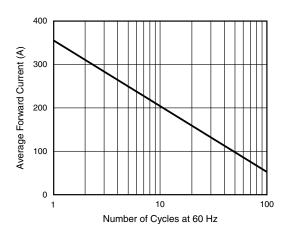


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode



### Vishay General Semiconductor

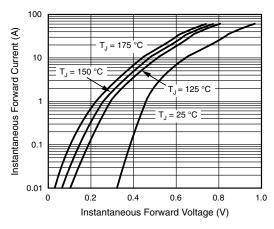


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

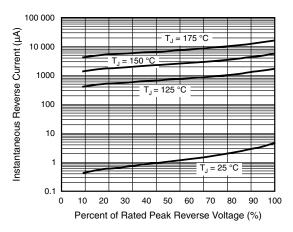


Fig. 4 - Typical Reverse Characteristics Per Diode

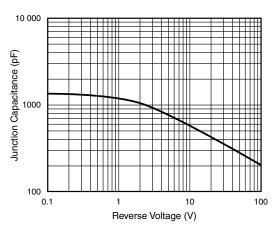


Fig. 5 - Typical Junction Capacitance Per Diode

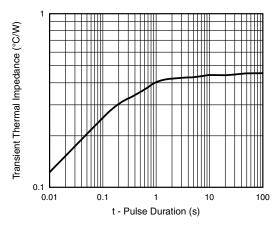
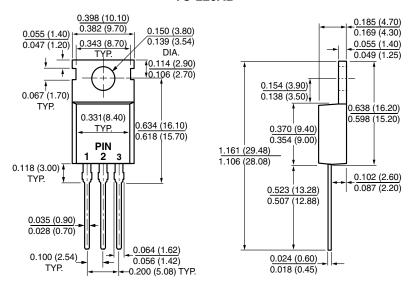


Fig. 6 - Typical Transient Thermal Impedance Per Diode

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### TO-220AB



Revision: 13-Aug-13 Document Number: 88892



### **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

## **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000